

## 5-V, Zero-Drift Operational Amplifiers

### Features

- Supply Voltage: 2.7 V to 5.5 V
- Offset Voltage:  $\pm 45 \mu\text{V}$  Maximum within Temperature Range from  $-40^\circ\text{C}$  to  $125^\circ\text{C}$
- Offset Voltage Drift:  $0.01 \mu\text{V}/^\circ\text{C}$
- Rail-to-Rail Input and Output
- Bandwidth: 3.5 MHz
- Slew Rate:  $4.7 \text{ V}/\mu\text{s}$
- Low Noise:  $12 \text{ nV}/\sqrt{\text{Hz}}$  at 1 kHz
- AEC-Q100 Qualified for Automotive Applications, Grade 1:  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  Ambient Operating Temperature Range

### Applications

- On-Board Charger
- Motor Control
- Automotive Current Measurement

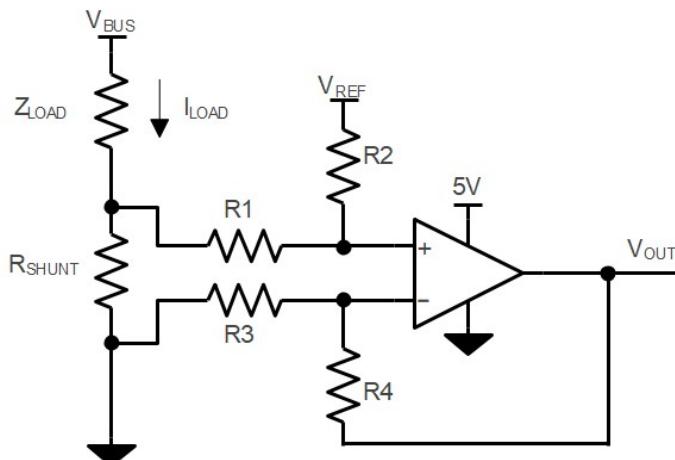
### Description

The TPA5561Q and TPA5562Q devices are single and dual operational amplifiers. The devices have very low offset voltage within the operating temperature range by the zero-drift technology. The offset voltage of the device is  $\pm 45 \mu\text{V}$  maximum within the temperature range from  $-40^\circ\text{C}$  to  $125^\circ\text{C}$ .

The TPA5561Q and TPA5562Q devices provide rail-to-rail input and output. The devices have excellent AC performance with 3.5-MHz bandwidth,  $4.7\text{-V}/\mu\text{s}$  slew rate while drawing 0.5-mA quiescent current per amplifier.

The devices can be used in high-accuracy and high-speed signal conditions.

### Typical Application Circuit



$$V_{OUT} = (I_{LOAD} \times R_{SHUNT}) \times (R_2 / R_1) + V_{REF}$$

When  $R_3 = R_1$ ,  $R_2 = R_4$ ,  $R_{SHUNT} \ll R_1$

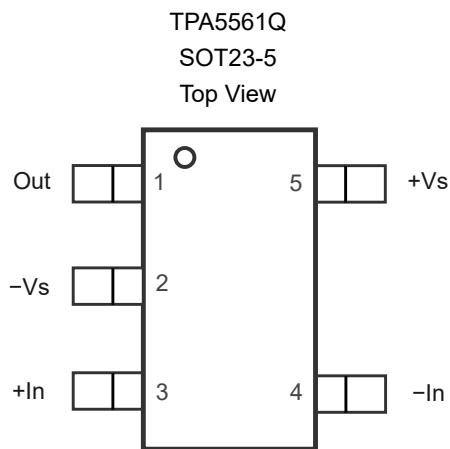
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## Revision History

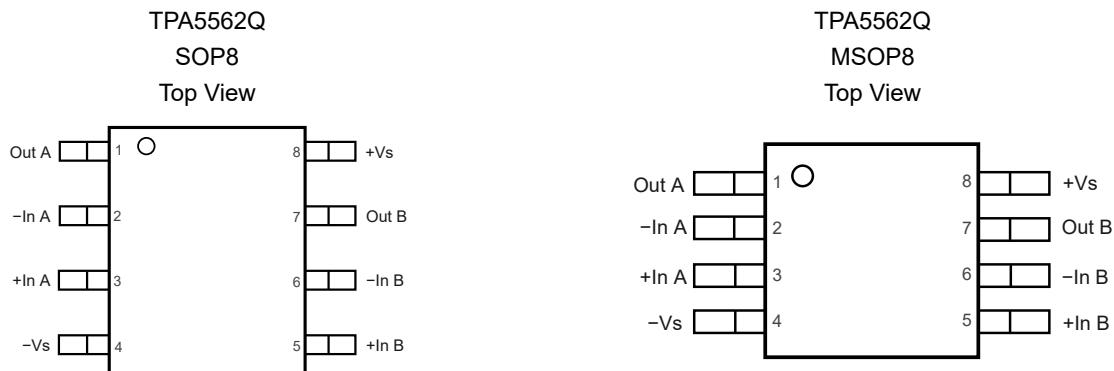
Date	Revision	Notes
2022-12-25	Rev.A.0	Initial version.
2024-04-28	Rev.A.1	Removed the label of TPA5562Q-SO1R-S and TPA5562Q-VS1R-S indicating future products in the Order Information.
2024-12-06	Rev.A.2	Corrected handwriting errors. The physical object has not changed.

## Pin Configuration and Functions



**Table 1. Pin Functions: TPA5561Q**

Pin No.	Name	I/O	Description
1	Out	O	Output
2	-Vs	-	Negative power supply
3	+In	I	Noninverting input
4	-In	I	Inverting input
5	+Vs	-	Positive power supply

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**Table 2. Pin Functions: TPA5562Q**

Pin No.	Name	I/O	Description
1	Out A	O	Output
2	-In A	I	Inverting input
3	+In A	I	Noninverting input
4	-Vs	-	Negative power supply
5	+In B	I	Noninverting input
6	-In B	I	Inverting input
7	Out B	O	Output
8	+Vs	-	Positive power supply

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### Specifications

#### Absolute Maximum Ratings (1)

Parameter		Min	Max	Unit
	Supply Voltage, (+Vs) – (–Vs)		6.5	V
	Input Voltage	(–Vs) – 0.3	(+Vs) + 0.3	V
	Differential Input Voltage	(–Vs) – (+Vs)	(+Vs) – (–Vs)	V
	Input Current: +IN, –IN (2)	–10	+10	mA
	Output Short-Circuit Duration (3)		Infinite	
T <sub>J</sub>	Maximum Junction Temperature		150	°C
T <sub>A</sub>	Operating Temperature Range	–40	125	°C
T <sub>STG</sub>	Storage Temperature Range	–65	150	°C
T <sub>L</sub>	Lead Temperature (Soldering 10 sec)		260	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

(2) The inputs are protected by ESD protection diodes to the power supply. If the input extends more than 300 mV beyond the power supply, the input current should be limited to less than 10 mA.

(3) A heat sink may be required to keep the junction temperature below the absolute maximum rating. This depends on the power dissipation of the application. Thermal resistance varies with the amount of PC board metal connected to the package.

#### ESD, Electrostatic Discharge Protection

Parameter		Condition	Minimum Level	Unit
HBM	Human Body Model ESD	AEC-Q100-002	3	kV
CDM	Charged Device Model ESD	AEC-Q100-011	1.5	kV
LU	Charged Device Model ESD	AEC-Q100-004, 25°C	400	mA
		AEC-Q100-004, 125°C	300	mA

#### Recommended Operating Conditions

Parameter		Min	Typ	Max	Unit
V <sub>s</sub>	Supply Voltage, (+Vs) – (–Vs)	2.7 (±1.35)		5.5 (±2.75)	V
T <sub>A</sub>	Operating Temperature Range	–40		125	°C

**5-V, Zero-Drift Operational Amplifiers****Thermal Information**

Package Type	$\theta_{JA}$	$\theta_{JC}$	Unit
SOT23-5	250	81	°C/W
SOP8	158	43	°C/W
MSOP8	210	45	°C/W

**5-V, Zero-Drift Operational Amplifiers**
**Electrical Characteristics**

All test conditions:  $V_S = 5 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $R_L = 10 \text{ k}\Omega$ , unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Power Supply</b>						
$V_S$	Supply Voltage Range		2.7		5.5	V
$I_Q$	Quiescent Current per Amplifier	$V_S = 5 \text{ V}$		0.5	1	mA
		$V_S = 5 \text{ V}, T_A = -40^\circ\text{C} \text{ to } 125^\circ\text{C}$			1.2	mA
PSRR	Power Supply Rejection Ratio	$V_S = 2.7 \text{ V} \text{ to } 5.5 \text{ V}, V_{CM} = 0 \text{ V}$	114	124		dB
		$V_S = 2.7 \text{ V} \text{ to } 5.5 \text{ V}, V_{CM} = 0 \text{ V}, T_A = -40^\circ\text{C} \text{ to } 125^\circ\text{C}$	110			dB
<b>Input Characteristics</b>						
$V_{OS}$	Input Offset Voltage	$V_S = 3.3 \text{ V}, V_{CM} = 0 \text{ to } 3.3 \text{ V}, T_A = -40^\circ\text{C} \text{ to } 125^\circ\text{C}$	-45		45	$\mu\text{V}$
		$V_S = 5 \text{ V}, V_{CM} = 0 \text{ to } 5 \text{ V}, T_A = -40^\circ\text{C} \text{ to } 125^\circ\text{C}$	-45		45	$\mu\text{V}$
$V_{OS\text{TC}}$	Input Offset Voltage Drift	$T_A = -40^\circ\text{C} \text{ to } 125^\circ\text{C}$		0.01		$\mu\text{V}/^\circ\text{C}$
$I_B$	Input Bias Current	$V_S = 5 \text{ V}, V_{CM} = 2.5 \text{ V}$		200	1000	pA
		$V_S = 5 \text{ V}, V_{CM} = 2.5 \text{ V}, T_A = -40^\circ\text{C} \text{ to } 125^\circ\text{C}$		300	1300	pA
$I_{OS}$	Input Offset Current	$V_S = 5 \text{ V}, V_{CM} = 2.5 \text{ V}$		100	600	pA
		$V_S = 5 \text{ V}, V_{CM} = 2.5 \text{ V}, T_A = -40^\circ\text{C} \text{ to } 125^\circ\text{C}$			850	pA
$C_{IN}$	Input Capacitance	Differential Mode		5		pF
		Common Mode		2.5		pF
$A_V$	Open-Loop Voltage Gain	$R_{LOAD} = 10 \text{ k}\Omega, V_{OUT} = 0.5 \text{ V} \text{ to } 4.5 \text{ V}$	120	150		dB
		$R_{LOAD} = 10 \text{ k}\Omega, V_{OUT} = 0.5 \text{ V} \text{ to } 4.5 \text{ V}, T_A = -40^\circ\text{C} \text{ to } 125^\circ\text{C}$	115			dB
$V_{CMR}$	Common-Mode Input Voltage Range		$(-V_S) - 0.1$		$(+V_S) + 0.1$	V
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 0 \text{ V} \text{ to } 5 \text{ V}$	115	140		dB
		$V_{CM} = 0 \text{ V} \text{ to } 5 \text{ V}, T_A = -40^\circ\text{C} \text{ to } 125^\circ\text{C}$	110			dB

**5-V, Zero-Drift Operational Amplifiers**
**Electrical Characteristics (Continued)**

All test conditions:  $V_S = 5 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $R_L = 10 \text{ k}\Omega$ , unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Output Characteristics</b>						
	Output Swing from Positive Rail	$R_{LOAD} = 10 \text{ k}\Omega$ to $V_S / 2$		10	20	mV
		$R_{LOAD} = 10 \text{ k}\Omega$ to $V_S / 2$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$			25	mV
		$R_{LOAD} = 2 \text{ k}\Omega$ to $V_S / 2$		45	100	mV
		$R_{LOAD} = 2 \text{ k}\Omega$ to $V_S / 2$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$			120	mV
	Output Swing from Negative Rail	$R_{LOAD} = 10 \text{ k}\Omega$ to $V_S / 2$		10	20	mV
		$R_{LOAD} = 10 \text{ k}\Omega$ to $V_S / 2$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$			25	mV
		$R_{LOAD} = 2 \text{ k}\Omega$ to $V_S / 2$		25	50	mV
		$R_{LOAD} = 2 \text{ k}\Omega$ to $V_S / 2$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$			80	mV
I <sub>SC</sub>	Output Short-Circuit Current	Sink or Source	40	60		mA
		Sink or Source, $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$	30			mA
<b>AC Specifications</b>						
GBW	Gain-Bandwidth Product			3.5		MHz
SR	Slew Rate	G = 1		4.7		V/ $\mu$ s
t <sub>OR</sub>	Overload Recovery			0.8		$\mu$ s
t <sub>S</sub>	Settling Time, 0.1%	G = 1, 2-V Step		8		$\mu$ s
PM	Phase Margin	$R_L = 10 \text{ k}\Omega$ , $C_L = 100 \text{ pF}$		70		°
GM	Gain Margin	$R_L = 10 \text{ k}\Omega$ , $C_L = 100 \text{ pF}$		15		dB
<b>Noise Performance</b>						
E <sub>N</sub>	Input Voltage Noise	f = 0.1 Hz to 10 Hz		0.25		$\mu$ V <sub>PP</sub>
e <sub>N</sub>	Input Voltage Noise Density	f = 1 kHz		12		nV/ $\sqrt{\text{Hz}}$
i <sub>N</sub>	Input Current Noise Density	f = 1 kHz		100		fA/ $\sqrt{\text{Hz}}$
THD+N	Total Harmonic Distortion and Noise	f = 1 kHz, G = 1, $R_L = 2 \text{ k}\Omega$ , $V_{OUT} = 1 \text{ V}_{RMS}$		0.005		%

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### Typical Performance Characteristics

All test conditions:  $V_S = 5$  V,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

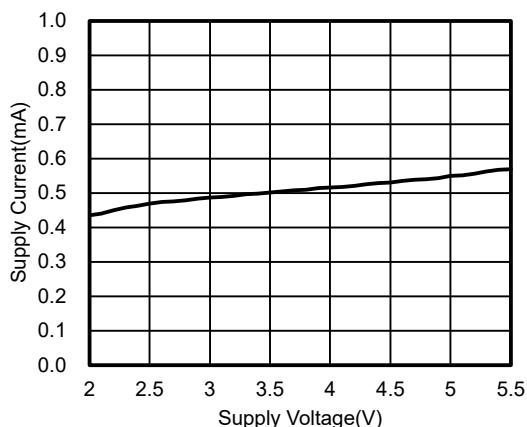


Figure 1. Supply Current vs. Supply Voltage, 1ch

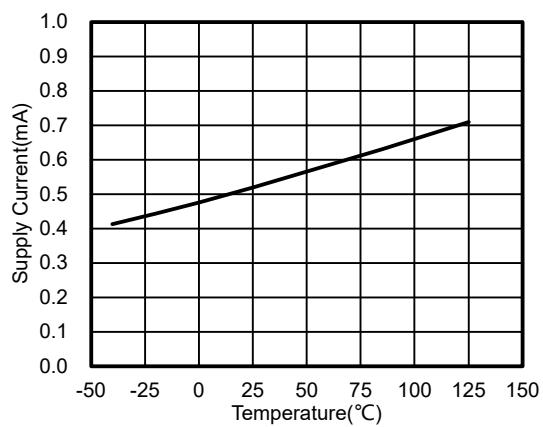


Figure 2. Supply Current vs. Temperature, 1ch

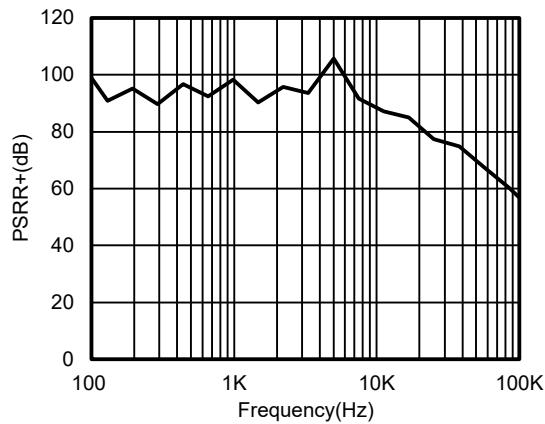


Figure 3. PSRR+ vs. Frequency

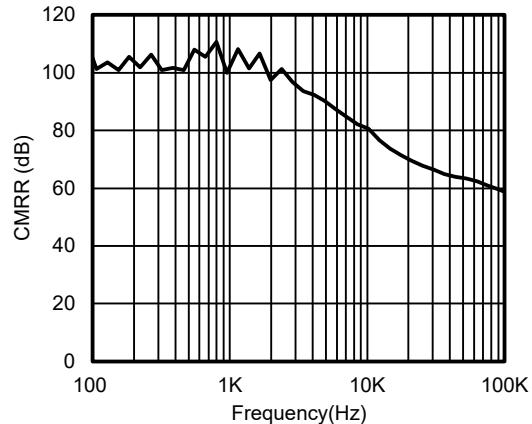


Figure 4. PSRR- vs. Frequency

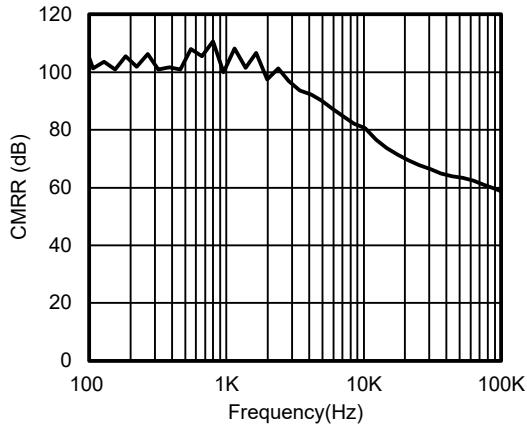


Figure 5. CMRR vs. Frequency

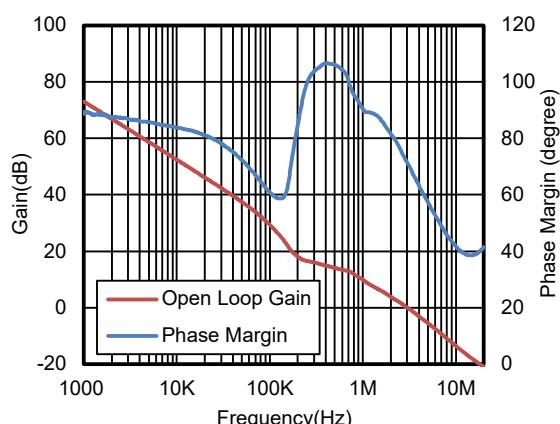
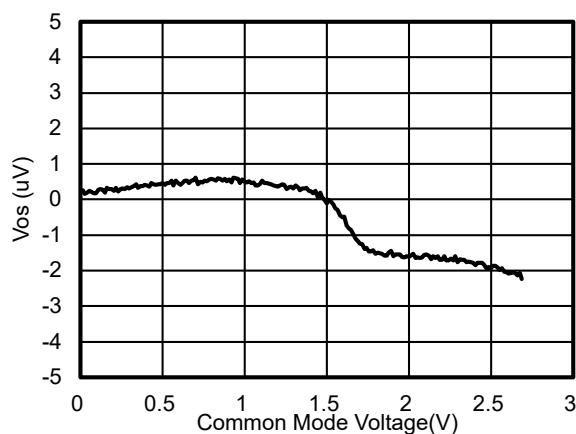
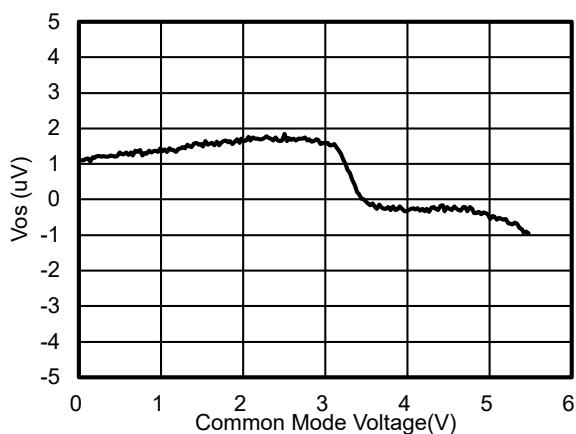
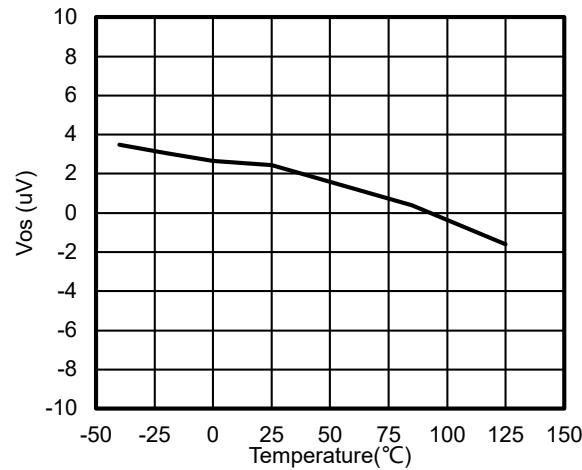
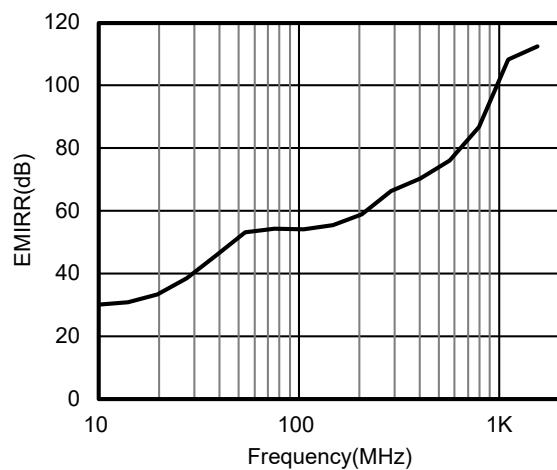
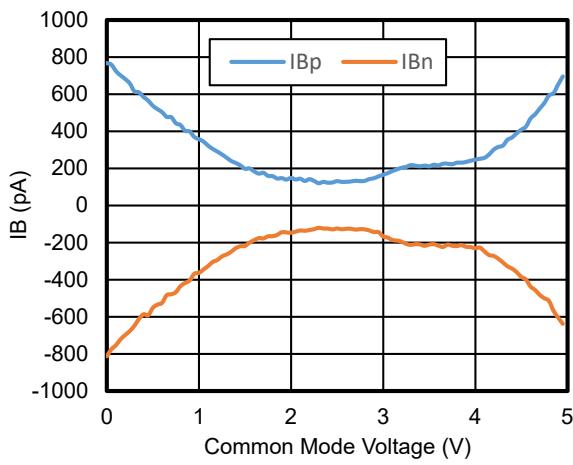
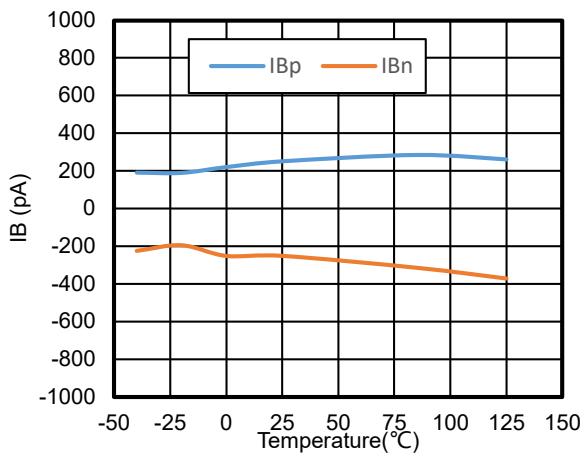
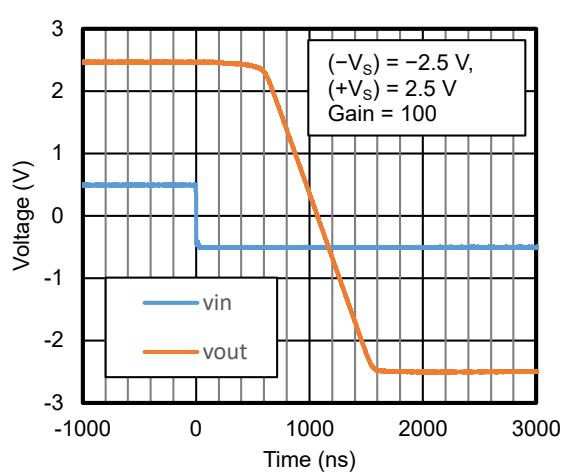
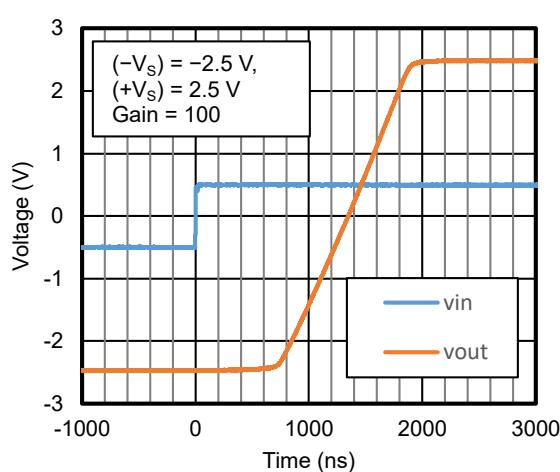
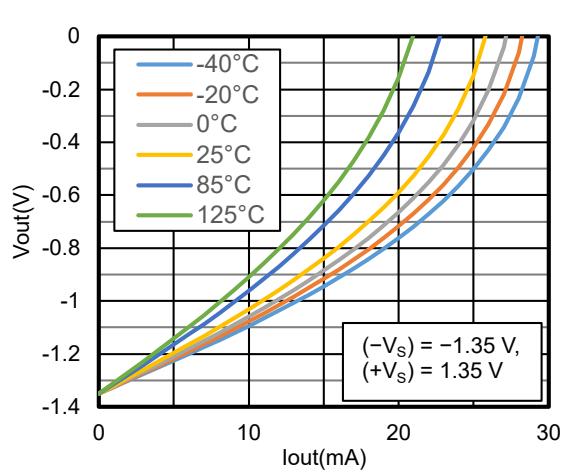
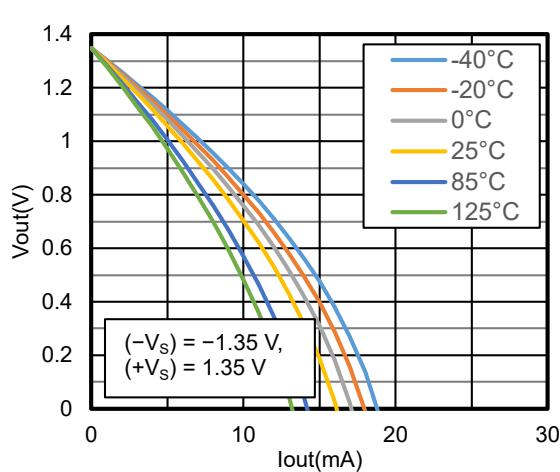
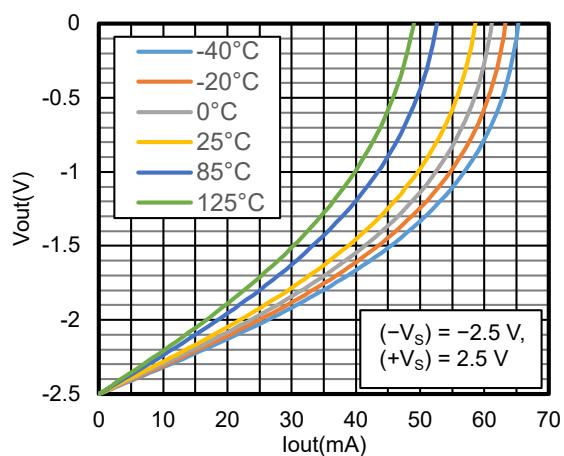
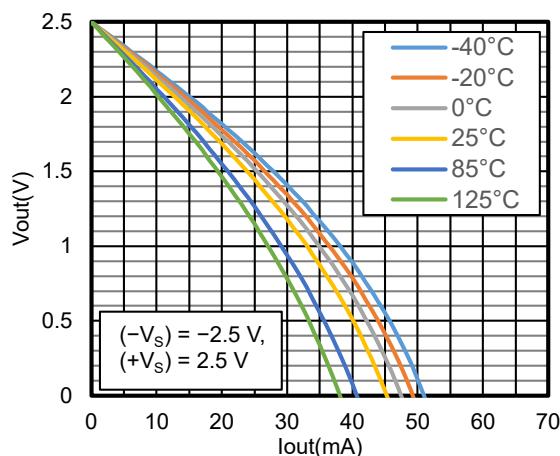
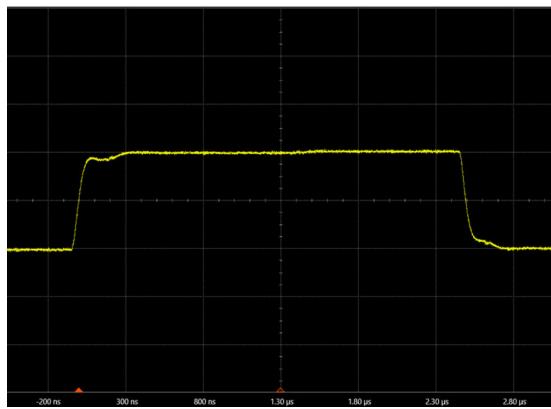


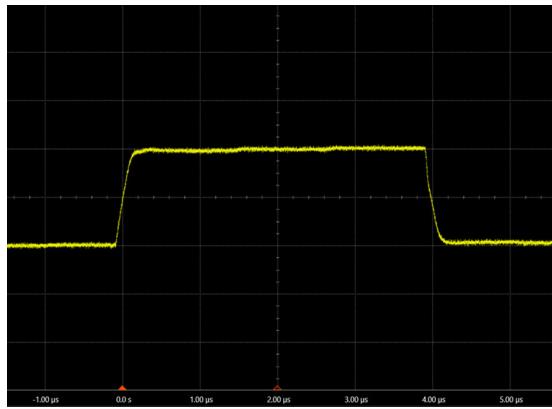
Figure 6. Open-Loop Gain and Phase Margin vs. Frequency,  $R_L = 10$  kΩ,  $C_L = 100$  pF

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**Figure 7.**  $V_{os}$  vs.  $V_{CM}$ ,  $V_S = 2.7$  V

**Figure 8.**  $V_{os}$  vs.  $V_{CM}$ ,  $V_S = 5.5$  V

**Figure 9.**  $V_{os}$  vs. Temperature

**Figure 10.** EMIRR vs. Frequency

**Figure 11.**  $I_B$  vs. Common-Mode Voltage

**Figure 12.**  $I_B$  vs. Temperature

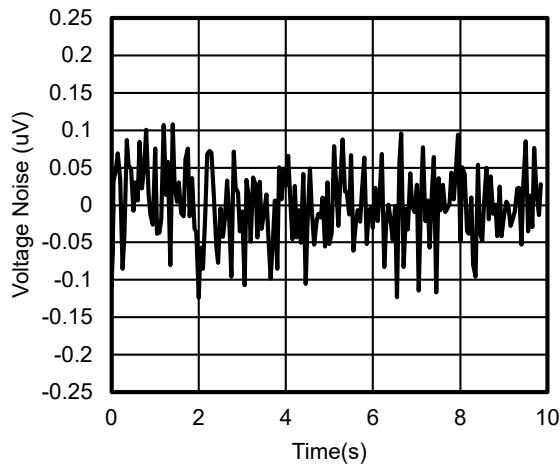
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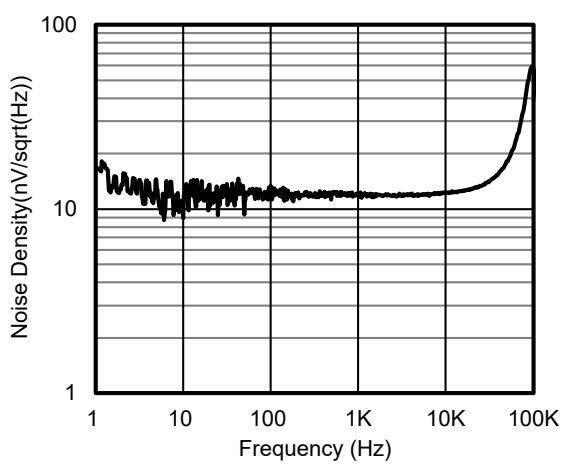
**Figure 19. 100-mV Small-Signal Step Response Voltage:**  
50 mV/div, Time: 500 ns/div



**Figure 20. 1-V Large-Signal Step Response Voltage: 500**  
mV/div, Time: 1 µs/div



**Figure 21. 0.1-Hz to 10-Hz Voltage Noise**



**Figure 22. Voltage Noise Spectral Density vs. Frequency**

## Detailed Description

### Overview

The TPA556xQ series of op amps can operate on a single-supply voltage (2.7 V to 5.5 V), or a split-supply voltage ( $\pm 1.35$  V to  $\pm 2.75$  V), making them highly versatile and easy to use. The power-supply pins should have local bypass ceramic capacitors (typically 0.01  $\mu$ F to 0.1  $\mu$ F). These amplifiers are fully specified from 2.7 V to 5.5 V and over the extended temperature range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ .

### Functional Block Diagram

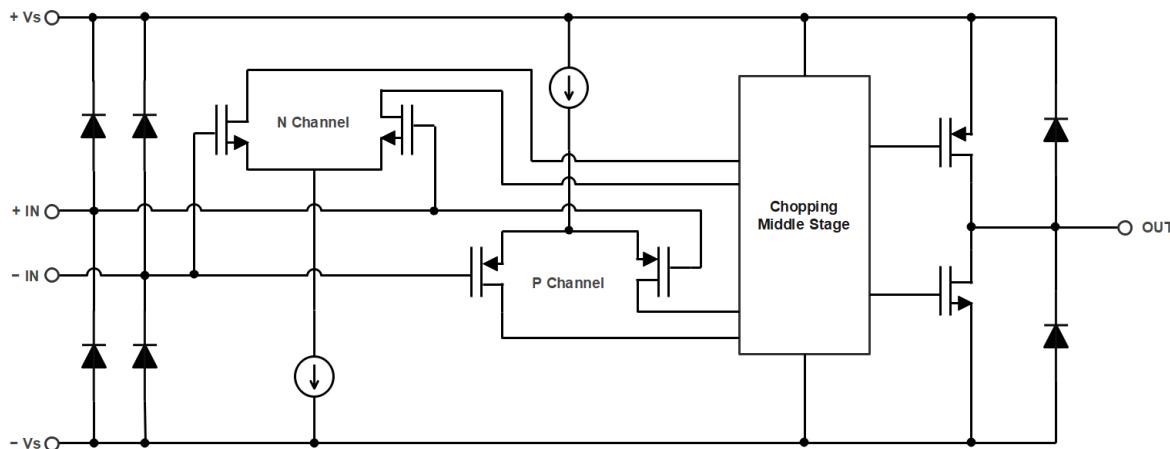


Figure 23. Functional Block Diagram

## Feature Description

### Operating Voltage

The devices are designed for single supply operation from 2.7 V to 5.5 V or dual supply operation from  $\pm 1.35$  V to  $\pm 2.75$  V.

### Ultra Low Offset Voltage and Offset Voltage Drift in Operating Temperature Range

The devices provide 45- $\mu$ V offset voltage within the temperature range from  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ , which is achieved through the chopper stabilized technology. This unique topology allows the devices to maintain their low-offset voltage over a wide temperature range and their operating lifetime.

### Low 1/f Noise

Flicker noise, also known as 1/f noise, is inherent in semiconductor devices and increases as frequency decreases. The flicker noise provides higher degrees of error for low-frequency applications. The devices use the chopper stabilized technology to reduce flicker noise. This reduction in 1/f noise allows the devices to have lower noise at DC and low-frequency range compared to standard amplifiers.

### Residual Voltage Ripple

The chopping technique can be used in amplifier design due to the internal notch filter. Although the chopping-related voltage ripple is suppressed, a higher noise spectrum exists at the chopping frequency and its harmonics due to residual ripple.

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The devices set the chopping frequency to 450 kHz. If the frequency of the input signal is close to the chopping frequency, the signal may be interfered with by the residue ripple. To suppress the noise at the chopping frequency, it is recommended that a post filter be placed at the output of the amplifier.

**Rail-to-Rail Input**

The input common-mode voltage range of the devices extends 100 mV beyond the supply rails. This performance is achieved with a complementary input stage: a PMOS input differential pair in parallel with an NMOS input differential pair.

**Rail-to-Rail Output**

The devices deliver rail-to-rail output swing capability with a class-AB output stage. Different load conditions change the ability of the amplifier to swing close to the rails.

## Application and Implementation

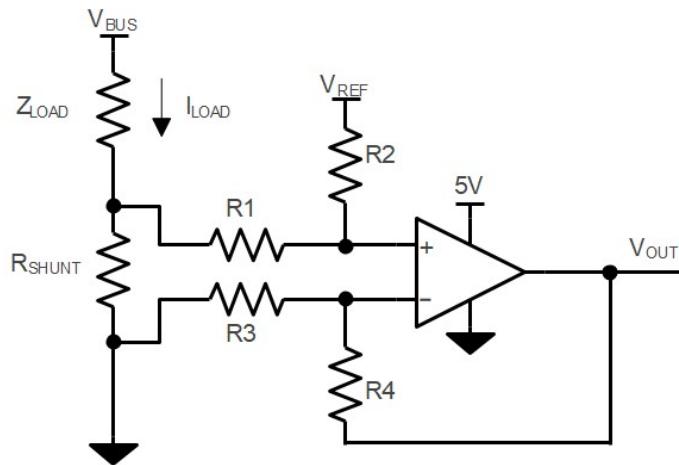
### Note

Information in the following application sections is not part of the 3PEAK's component specification and 3PEAK does not warrant its accuracy or completeness. 3PEAK's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## Application Information

### Low-Side Current-Sensing Application

Figure 24 shows the device configured in a low-side current sensing application. The low-side current sensing method consists of placing a sense resistor between the load and the circuit ground. The voltage dropping across the resistor is amplified by different amplifier circuits with the device.  $V_{REF}$  can be used to add bias voltage to the output voltage. Particular attention must be paid to the matching and precision of R1, R2, R3, and R4, to maximize the accuracy of the measurement.



$$V_{OUT} = (I_{LOAD} \times R_{SHUNT}) \times (R2 / R1) + V_{REF}$$

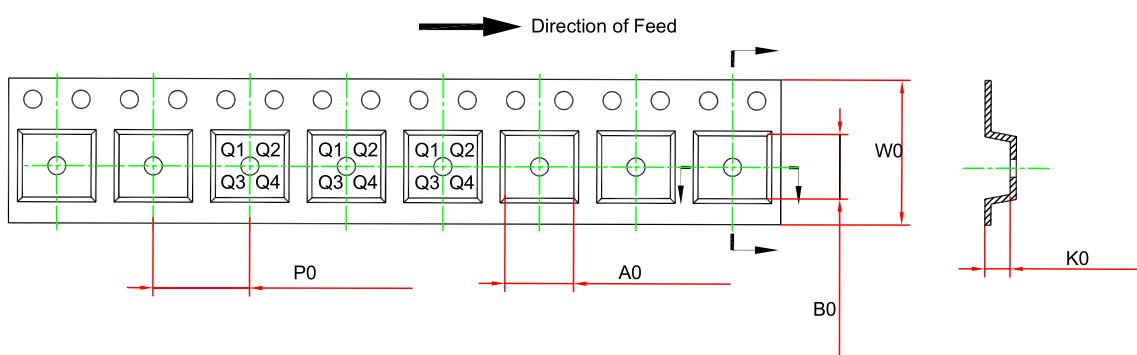
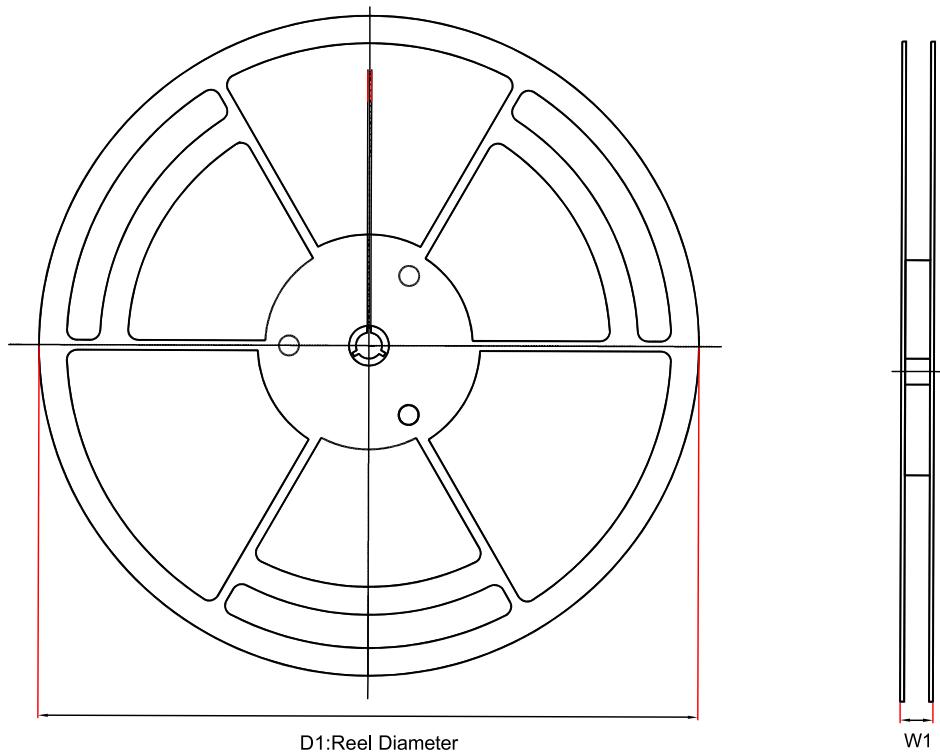
When  $R3 = R1$ ,  $R2 = R4$ ,  $R_{SHUNT} \ll R1$

Figure 24. Low-Side Current-Sensing Application

### Power Supply Recommendations

Place 0.1- $\mu$ F bypass capacitors close to the power supply pins to reduce coupling errors from the noise or high-impedance power supplies.

## Tape and Reel Information



Order Number	Package	D1 (mm)	W1 (mm)	A0 (mm) <sup>(1)</sup>	B0 (mm) <sup>(1)</sup>	K0 (mm) <sup>(1)</sup>	P0 (mm)	W0 (mm)	Pin1 Quadrant
TPA5561Q-S5TR-S	SOT23-5	180.0	13.1	3.2	3.2	1.4	4.0	8.0	Q3
TPA5562Q-SO1R-S	SOP8	330.0	17.6	6.4	5.4	2.1	8.0	12.0	Q1
TPA5562Q-VS1R-S	MSOP8	330.0	17.6	5.2	3.3	1.5	8.0	12.0	Q1

(1) The value is for reference only. Contact the 3PEAK factory for more information.

## Package Outline Dimensions

SOT23-5

Package Outline Dimensions		S5T(SOT23-5-A)			
Symbol	Dimensions In Millimeters		Dimensions In Inches		
	MIN	MAX	MIN	MAX	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.150	0.000	0.006	
A2	1.000	1.200	0.039	0.047	
b	0.280	0.500	0.011	0.020	
c	0.100	0.230	0.004	0.009	
D	2.820	3.020	0.111	0.119	
E	2.600	3.000	0.102	0.118	
E1	1.500	1.720	0.059	0.068	
e	0.950 BSC		0.037 BSC		
L	0.300	0.600	0.012	0.024	
$\theta$	0	8°	0	8°	

**NOTES**

1. Do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

**SOP8**

Package Outline Dimensions		SO1(SOP-8-A)			
Symbol	Dimensions In Millimeters		Dimensions In Inches		
	MIN	MAX	MIN	MAX	
A	1.350	1.750	0.053	0.069	
A1	0.050	0.250	0.002	0.010	
A2	1.250	1.550	0.049	0.061	
b	0.330	0.510	0.013	0.020	
c	0.170	0.250	0.007	0.010	
D	4.700	5.100	0.185	0.201	
E	5.800	6.200	0.228	0.244	
E1	3.800	4.000	0.150	0.157	
e	1.270 BSC		0.050 BSC		
L	0.400	1.000	0.016	0.039	
$\theta$	0	8°	0	8°	

**NOTES**

1. Do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

**MSOP8**

Package Outline Dimensions		VS1(MSOP-8-A)			
Symbol	Dimensions In Millimeters		Dimensions In Inches		
	MIN	MAX	MIN	MAX	
A	0.800	1.100	0.031	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.250	0.380	0.010	0.015	
c	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
E	4.700	5.100	0.185	0.201	
E1	2.900	3.100	0.114	0.122	
e	0.650 BSC		0.026 BSC		
L	0.400	0.800	0.016	0.031	
θ	0	8°	0	8°	

**NOTES**

1. Do not include mold flash or protrusion.
2. This drawing is subject to change without notice.



TPA5561Q/TPA5562Q

5-V, Zero-Drift Operational Amplifiers

## Order Information

Order Number	Operating Temperature Range	Package	Marking Information	MSL	Transport Media, Quantity	Eco Plan
TPA5561Q-S5TR-S	-40 to 125°C	SOT23-5	56Q	MSL 3	Tape and Reel, 3000	Green
TPA5562Q-SO1R-S	-40 to 125°C	SOP8	5562Q	MSL 1	Tape and Reel, 4000	Green
TPA5562Q-VS1R-S	-40 to 125°C	MSOP8	5562Q	MSL 1	Tape and Reel, 3000	Green

**Green:** 3PEAK defines "Green" to mean RoHS compatible and free of halogen substances.

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